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National Semiconductor

100323 Low Power Hex Bus Driver

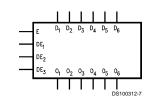
General Description

The 100323 is a monolithic device containing six bus drivers capable of driving terminated lines with terminations as low as 25Ω . To reduce crosstalk, each output has its own respective ground connection. Transition times were designed to be longer than on other F100K devices. The driver itself performs the positive logic AND of a data input (D₁-D₆) and the OR of two select inputs (E and either DE₁, DE₂, or DE₃). Enabling of data is possible in multiples of two, i.e., 2, 4 or all

6 paths. All inputs have 50 k Ω pull-down resistors.

The output voltage LOW level is designed to be more negative than normal ECL outputs (cut off state). This allows an

Logic Symbol



emitter-follower output transistor to turn off when the termination supply is -2.0V and thus present a high impedance to the data bus.

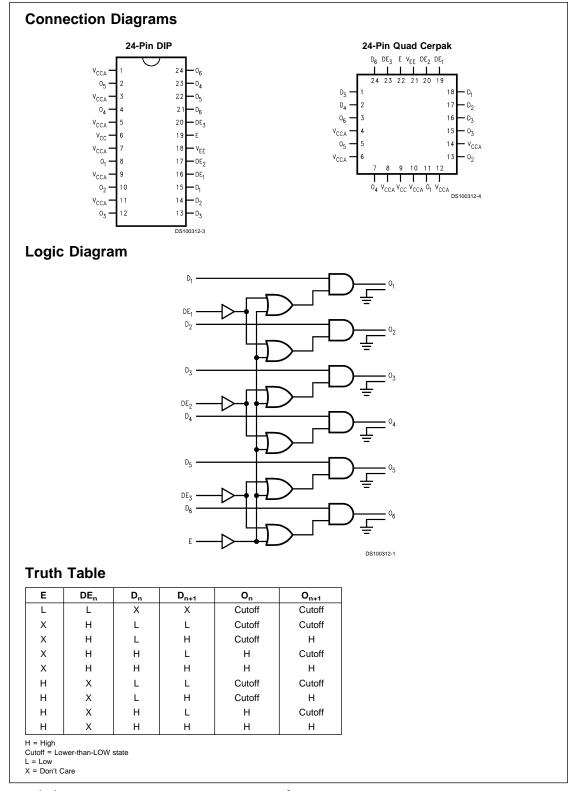
Features

- 50% power reduction of the 100123
- 2000V ESD protection
- -4.2V to -5.7V operating range
- Drives 25Ω load

00323 Low Power Hex Bus Driver

Pin Names	Description
D ₁ -D ₆	Data Inputs
D ₁ -D ₆ DE ₁ -DE ₃	Dual Enable Inputs
E	Common Enable Input
0 ₁ -0 ₆	Data Outputs

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature	–65°C to +150°C
Maximum Junction Temperature	
Ceramic	+175°C
V _{EE} Pin Potential to Ground Pin	-7.0V to +0.5V
Input Voltage (DC)	V _{EE} to +0.5V
Output Current (DC Output High)	–50 mA
ESD	≥2000V

Recommended Operating Conditions

Case Temperature

Military Supply Voltage (V_{EE})

-55°C to +125°C -5.7V to -4.2V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: ESD testing conforms to MIL-STD-883, Method 3015.

Military Version

DC Electrical Characteristics

 $V_{\rm EE}$ = -4.2V to -5.7V, $V_{\rm CC}$ = $V_{\rm CCA}$ = GND, $T_{\rm C}$ = -55°C to +125°C

Symbol	Parameter	Min	Max	Units	Тc	Conditions		Notes
V _{OH}	Output HIGH	-1025	-870	mV	0°C to +125°C	$V_{IN} = V_{IH (max)}$	Loading with	(Notes 3, 4, 5)
	Voltage	-1085	-870	mV	–55°C	or V _{IL (min)}	25Ω to -2.0V	
V _{OHC}	Output HIGH	-1035		mV	0°C to +125°C	$V_{IN} = V_{IH (min)}$	Loading with	(Notes 3, 4, 5)
	Voltage	-1085		mV	–55°C	or V _{IL (max)}	25Ω to -2.0V	
V _{OLC}	Output LOW		-1610	mV	0°C to +125°C			
	Voltage		-1555	MV	–55°C			
V _{OLZ}	Cut-Off LOW		-1950	mV	0°C to +125°C	$V_{IN} = V_{IH (min)}$	Loading with	(Notes 3, 4, 5)
	Voltage		-1850	1	–55°C	or V _{IL (max)}	25Ω to -2.0V	
VIH	Input HIGH	-1165	-870	mV	–55°C to +125°C	Guaranteed HIGH	l Signal	(Notes 3, 4, 5, 6)
	Voltage					for All Inputs		
VIL	Input LOW	-1830	-1475	mV	–55°C to +125°C	Guaranteed LOW	Signal	(Notes 3, 4, 5, 6)
	Voltage					for All Inputs		
IIL	Input LOW	0.50		μA	–55°C to +125°C	V _{EE} = 4.2V, V _{IN} =	= V _{IL (min)}	(Notes 3, 4, 5)
	Current							
IIH	Input HIGH		240	μA	0°C to +125°C	$V_{EE} = -5.7V, V_{IN}$	= V _{IH (max)}	(Notes 3, 4, 5)
	Current		340	μA	–55°C			
I _{EE}	Power Supply					Inputs Open		
	Current	-155	-53	mA	–55°C to +125°C	$V_{EE} = -4.2V$ to -	5.7V	(Notes 3, 4, 5)

Note 3: F100K 300 Series cold temperature testing is performed by temperature soaking (to guarantee junction temperature equals -55°C), then testing immediately without allowing for the junction temperature to stabilize due to heat dissipation after power-up. This provides "cold start" specs which can be considered a worst case condition at cold temperatures.

Note 4: Screen tested 100% on each device at -55°C, +25°C, and +125°C, Subgroups 1, 2, 3, 7, and 8.

Note 5: Sample tested (Method 5005, Table I) on each manufactured lot at -55°C, +25°C, and +125°C, Subgroups A1, 2, 3, 7, and 8.

Note 6: Guaranteed by applying specified input condition and testing $V_{OH}\!/\!V_{OL}$.

AC Electrical Characteristics

 V_{EE} = -4.2V to -5.7V, V_{CC} = V_{CCA} = GND

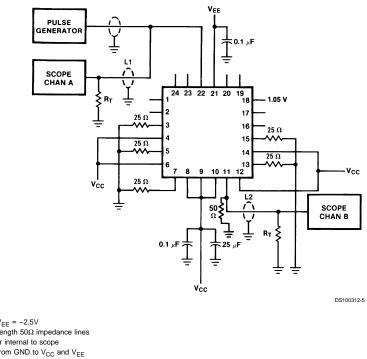
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Symbol	Parameter	T _c =	–55°C	$T_c = +25^{\circ}C$ T_c		T _c = -	T _c = +125°C		Conditions
		Min	Max	Min	Max	Min	Max]	
t _{PZH}	Propagation Delay	0.70	3.70	1.10	3.60	1.20	3.60	ns	Figures 1, 2
t _{PHZ}	Data to Output	0.50	3.60	1.10	3.10	1.20	3.50		
t _{PZH}	Propagation Delay	0.60	3.60	1.10	3.60	1.30	3.80	ns	
t _{PHZ}	Data Enable to Output	1.00	4.20	1.50	3.60	1.60	4.00		
t _{PZH}	Propagation Delay	0.70	3.60	1.00	3.50	1.20	3.60	ns	
t _{PHZ}	Common Enable to Output	0.90	4.00	1.40	3.40	1.40	3.80		
t _{TZH}	Transition Time	0.20	2.00	0.20	2.00	0.20	2.00	ns	
t _{THZ}	20% to 80%, 80% to 20%	0.20	1.80	0.20	1.60	0.20	1.60		

Note 7: The specified limits represent the "worst case" value for the parameter. Since these "worst case" values normally occur at the temperature extremes, additional noise immunity and guard banding can be achieved by decreasing the allowable system operating ranges.

Note 8: Conditions for testing shown in the tables are chosen to guarantee operation under "worst case" conditions.

Test Circuitry

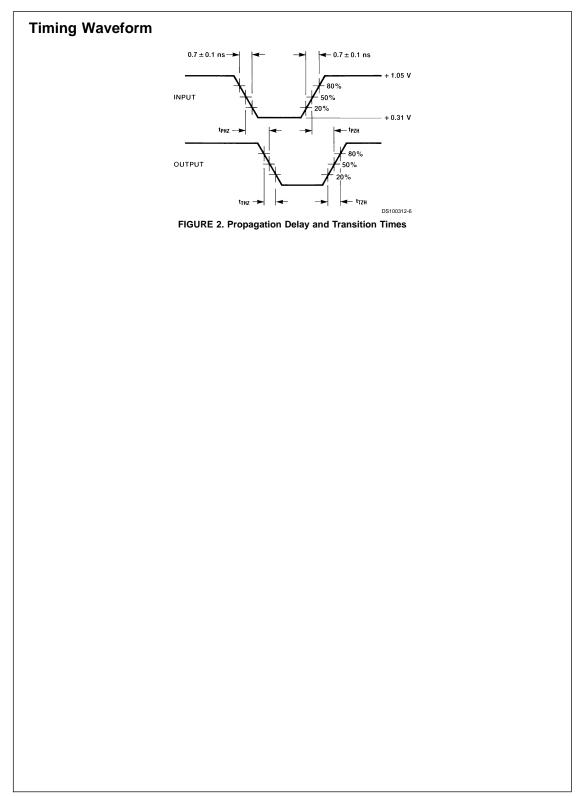


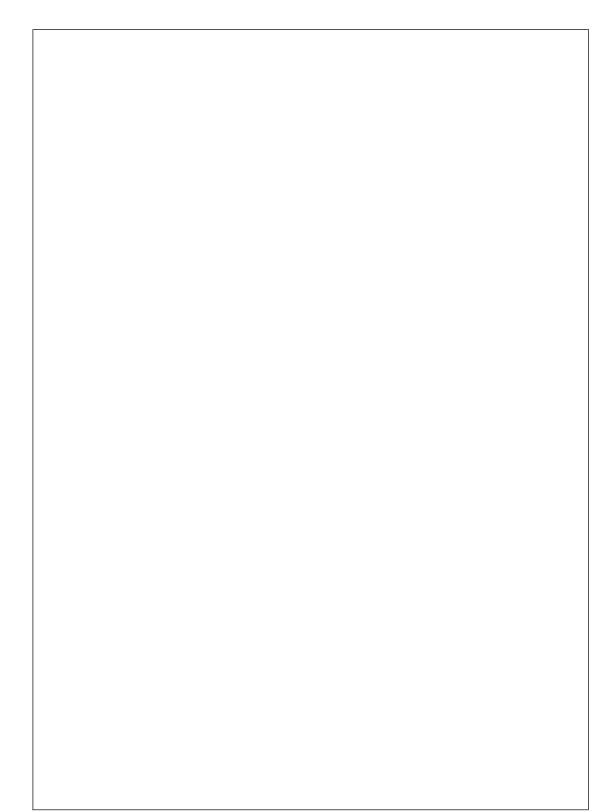
Notes:

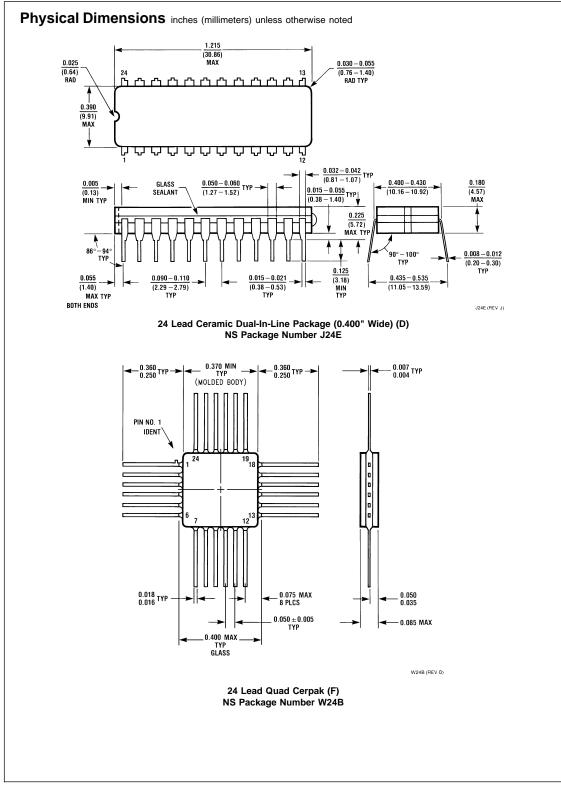
 $\begin{array}{l} \text{Notes.} \\ \text{V_{CC}}, \text{V}_{CCA} = +2\text{V}, \text{V}_{EE} = -2.5\text{V} \\ \text{L1 and L2} = \text{equal length } 50\Omega \text{ impedance lines} \\ \text{R}_{T} = 50\Omega \text{ terminator internal to scope} \\ \text{Decoupling 0.1 } \mu\text{F from GND to V}_{CC} \text{ and V}_{EE} \\ \text{All unused outputs are loaded with } 25\Omega \text{ to GND} \\ \text{C}_{L} = \text{Fixture and stray capacitance} \leq 3 \text{ pF} \\ \text{Pin numbers shown are for flatpak; for DIP see logic symbol} \end{array}$

FIGURE 1. AC Test Circuit

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